

1a)

p-type every boron atom adds a hole $n_p = 10^{16} \text{ / cm}^3$

How many electrons? \rightarrow Law of mass action

$$np = n_i^2 \quad n = \frac{n_i^2}{p}$$

$$n = \frac{(1,5 \cdot 10^{10} \text{ / cm}^3)^2}{10^{16} \text{ / cm}^3} = 2,25 \cdot 10^4 \text{ / cm}^3$$

n-type: every phosphorus adds a electron $n_n = 10^{18} \text{ / cm}^3$

How many holes? \rightarrow Law of mass action

$$np = n_i^2 \quad p = \frac{n_i^2}{n}$$

$$p = \frac{(1,5 \cdot 10^{10} \text{ / cm}^3)^2}{10^{18} \text{ / cm}^3} = 1,5 \cdot 10^{-22.5} \text{ cm}^{-3}$$

b) The voltage is dependent on the doping concentration via:

$$N_A N_D = (n_i)^2 e^{\left(\frac{V_{oc}}{k_B T}\right)}$$

$$\text{This becomes: } V_{oc} = \frac{k_B T}{q} \ln\left(\frac{N_A N_D}{n_i^2}\right) = \frac{1,38 \cdot 10^{-23} \cdot 300}{1,602 \cdot 10^{-19}} \ln\left(\frac{10^{18} \cdot 10^{18}}{(1,5 \cdot 10^{10})^2}\right) = 0.81 \text{ V}$$

c) Width of depletion region

$$W = \sqrt{\frac{2 \epsilon_0 \epsilon_r}{q} V_{oc} \left(\frac{1}{N_A} + \frac{1}{N_D}\right)} = \sqrt{\frac{2 \cdot 8.854 \cdot 10^{-12}}{1,602 \cdot 10^{-19}} \cdot 0.81 \text{ V} \left(\frac{1}{10^{18}} + \frac{1}{10^{18}}\right)} = 0.325 \mu\text{m}$$

2) Current of a p-n-junction under light:

$$J(V) = J_0 (e^{\frac{qV}{k_B T}} - 1) - J_{ph}$$

Since $J(V_{oc}) = 0$ it follows:

$$V_{oc} = \frac{k_B T}{q} \ln\left(\frac{J_{ph}}{J_0} + 1\right)^{\frac{1}{qV}} \cdot J(V) = \frac{1,38 \cdot 10^{-23} \cdot 300}{1,602 \cdot 10^{-19}} \ln\left(\frac{35}{1,35 \cdot 10^{-10}} + 1\right) = 0.67 \text{ V}$$

3)

Is it correct

because:

The open circuit voltage can be expressed as: $V_{oc} = \frac{2 k_B T}{q} \ln\left(\frac{J_{sc}}{n_i}\right)$

The doping increases the voltage by changing the fermi levels.

Very important for exam to know all J_{sc} , V_{oc} , J_{ph}

a) From the graph it looks like $I = 41 \text{ A}$

The solar cell area is $40 \text{ cm} \cdot 40 \text{ cm} = 1600 \text{ cm}^2 = A$

The current density is therefore: $J_{sc} = \frac{41 \text{ A}}{1600 \text{ cm}^2} = 0,0256 \text{ A/cm}^2 = 25,6 \text{ mA/cm}^2$



4)

b) From the graph it looks like $V(OC)=0,6V$
 The fill factor is therefore:

$$FF = \frac{P_{max}}{I_{sc} V_{oc}} = \frac{18,5W}{41A \cdot 0,6V} = 0,793$$

c) The efficiency is determined by comparing energy out to energy in:

$$\eta = \frac{P_{out}}{P_{in}} = \frac{FF \cdot V_{oc} \cdot I_{sc}}{P_{in}} = \frac{0,793 \cdot 0,6V \cdot 25mA}{100mW} = 12,2\%$$

d) The voltage drop can be determined by the formula:

$$\Delta U = \delta R \cdot I = 41A \cdot 0,002\Omega = 0,082V$$

The change in FF is proportional to the change in U

$$\Delta FF = \frac{\Delta U}{U} FF = \frac{0,082V}{0,6V} \cdot 0,793 = 0,108$$

The new FF is therefore $FF = 0,793 - 0,108 = 0,685$

